

DHG5I600PM

preliminary

Sonic Fast Recovery Diode

 $V_{RRM} = 600 V$

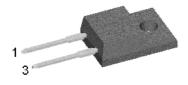
 $I_{FAV} = 5A$

 t_{rr} = 35 ns

High Performance Fast Recovery Diode Low Loss and Soft Recovery Single Diode

Part number

DHG5I600PM



Backside: isolated





Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low Irm-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low Irm reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: TO-220FP

- Isolation Voltage: 2500 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Base plate: Plastic overmolded tab
- Reduced weight

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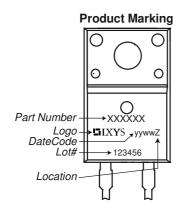
Fast Diode					Ratings		
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse blockir	ng voltage	$T_{VJ} = 25^{\circ}C$			600	V
V_{RRM}	max. repetitive reverse blocking vo	oltage	$T_{VJ} = 25^{\circ}C$			600	V
IR	reverse current, drain current	$V_R = 600 \text{ V}$	$T_{VJ} = 25^{\circ}C$			10	μΑ
		$V_R = 600 V$	$T_{VJ} = 125^{\circ}C$			1	mΑ
V _F	forward voltage drop	I _F = 5 A	$T_{VJ} = 25^{\circ}C$			2.21	V
		$I_F = 10 A$				3.07	٧
		I _F = 5 A	T _{vJ} = 125°C			2.17	V
		$I_F = 10 \text{ A}$				3.13	٧
I _{FAV}	average forward current	T _C = 85°C	T _{VJ} = 150°C			5	Α
		rectangular d = 0.5					1 1 1 1
V _{F0}	threshold voltage		$T_{VJ} = 150$ °C			1.14	V
r _F	slope resistance	ss calculation only				185	mΩ
R _{thJC}	thermal resistance junction to case)				4.2	K/W
R _{thCH}	thermal resistance case to heatsin	k			0.5		K/W
P _{tot}	total power dissipation		$T_C = 25^{\circ}C$			30	W
I _{FSM}	max. forward surge current	$t = 10 \text{ ms}$; (50 Hz), sine; $V_R = 0 \text{ V}$	$T_{VJ} = 45^{\circ}C$			40	Α
C¹	junction capacitance	$V_R = 400 V f = 1 MHz$	$T_{VJ} = 25^{\circ}C$		3		pF
I _{RM}	max. reverse recovery current		T _{VJ} = 25 °C		2		Α
		$I_F = 5 \text{ A}; V_R = 400 \text{ V}$ -di _F /dt = 100 A/ μ s	$T_{VJ} = {}^{\circ}C$		tbd		Α
t _{rr}	reverse recovery time	$-di_F/dt = 100 A/\mu s$	$T_{VJ} = 25 ^{\circ}C$		35		ns
	J		$T_{VJ} = {}^{\circ}C$		tbd		ns



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Package	Package TO-220FP				Ratings			
Symbol	Definition	Conditions			min.	typ.	max.	Unit
I _{RMS}	RMS current	per terminal					35	Α
T _{VJ}	virtual junction temperature				-55		150	°C
Top	operation temperature				-55		125	°C
T _{stg}	storage temperature				-55		150	°C
Weight						2		g
M _D	mounting torque				0.4		0.6	Nm
F _c	mounting force with clip				20		60	N
d _{Spp/App}	oroonago distanco on surfac	e striking distance through air	terminal to terminal	3.2	2.7			mm
$d_{Spb/Apb}$	creepage distance on surfac	e striking distance through air	terminal to backside	2.5	2.5			mm
V _{ISOL}	isolation voltage	t = 1 second	50/60 Hz, RMS; IsoL ≤ 1 mA		2500			٧
		t = 1 minute			2100			V



Part description

D = Diode H = Sonic Fast Recovery Diode

G = extreme fast

5 = Current Rating [A]

I = Single Diode

600 = Reverse Voltage [V] PM = TO-220ACFP (2)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DHG5I600PM	DHG5l600PM	Tube	50	504026

Similar Part	Package	Voltage class
DHG5I600PA	TO-220AC (2)	600

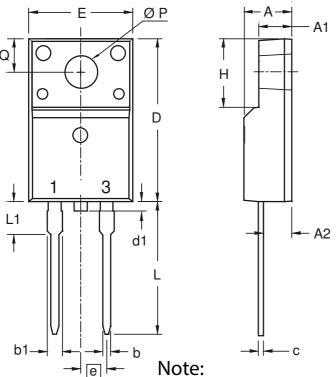
Equivalent Circuits for Simulation			* on die level	$T_{VJ} = 150^{\circ}C$
$I \rightarrow V_0$		Fast Diode		
V _{0 max}	threshold voltage	1.14		V
R _{0 max}	slope resistance *	182		mΩ





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Outlines TO-220FP



<u>→</u> e	Note:
	All metal surface are
	matte pure tin plated
	except trimmed area.

Dim.	Millim	Millimeters		nes
DIIII.	min	max	min	max
Α	4.50	4.90	0.177	0.193
A1	2.34	2.74	0.092	0.108
A2	2.56	2.96	0.101	0.117
b	0.70	0.90	0.028	0.035
b1	1.27	1.47	0.050	0.058
С	0.45	0.60	0.018	0.024
D	15.67	16.07	0.617	0.633
d1	0	1.10	0	0.043
Е	9.96	10.36	0.392	0.408
е	2.54	2.54 BSC		BSC
Н	6.48	6.88	0.255	0.271
L	12.68	13.28	0.499	0.523
L1	3.03	3.43	0.119	0.135
ØΡ	3.08	3.28	0.121	0.129
Q	3.20	3.40	0.126	0.134

